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Volume 34 Number 3 March 2013

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	Zhao Qiang, Zhou Maoxiu, Zhang Wei, Liu Qi, Li Xiaofeng, Liu Ming, and Dai Yuehua
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	V. K. Dwivedi, P. Srivastava, and G. Vijaya Prakash
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	Zhang Jijun, Wang Linjun, Min Jiahua, Qin Kaifeng, Shi Zhubin, and Liang Xiaoyan
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	Lu Jiang, Tian Xiaoli, Lu Shuojin, Zhou Hongyu, Zhu Yangjun, and Han Zhengsheng
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	Zhou Jianjun, Bai Song, Kong Cen, Geng Xijiao, Lu Haiyan, Kong Yuechan, and Chen Tangsheng
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Cao Yu, Zhang Jianjun, Li Tianwei, Huang Zhenhua, Ma Jun, Yang Xu, Ni Jian, Geng Xinhua, and Zhao Ying

034008

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025004	
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